Properties of films of mercury cuprates grown on CeO2 buffered R-cut sapphire and LaAlO3

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Abstract

Films of Hg-1212 have been made by RF sputtering and ex-situ mercurated on CeO2 buffered R cut sapphire or LaAlO3 (001) substrate. The elaboration process is descried and some relevant parameters of the epitaxial growth discussed in connection with thickness, composition. The films are surperconducting at 120 K from resistivity and susceptibility measurements. Some microwave properties are presented in view of practical applications such as filters. Finally attempts to pattern and micro-pattern some of these films are presented and resulting properties presented.

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